# NSN 5961-00-465-4926

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**Inclosure Material:** 

Metal

**Overall Length:** 

0.450 inches

#### **Overall Diameter:**

0.875 inches

## **Mounting Facility Quantity:**

2

### Internal Configuration:

Junction contact

## Electrode Internally-electrically Connected To Case:

Collector

#### **Mounting Method:**

Unthreaded hole

Features Provided:

#### Hermetically sealed case

Semiconductor Material:

Silicon

## Voltage Rating In Volts Per Characteristic:

120.0 breakdown voltage, collector-to-base, emitter open and 80.0 breakdown voltage, collector-to-emitter, base open and 8.0

breakdown voltage, emitter-to-base, collector open

## **Current Rating Per Characteristic:**

Between 2.00 amperes source cutoff current and 5.00 amperes source cutoff current

#### **Power Rating Per Characteristic:**

30.0 watts small-signal input power, common-collector

#### Maximum Operating Tempurature Per Measurement Point:

165.0 degrees celsius junction

#### **Special Features:**

Junction pattern arrangement: npn

#### **Terminal Type And Quantity:**

2 uninsulated wire lead and 1 case

#### **Specification Data:**

80131-release5277 professional/industrial association specification

#### Shelf Life:

N/a

## Unit Of Measure:

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#### Demilitarization:

No

#### Fiig:

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